



SANYO Semiconductors

DATA SHEET

An ON Semiconductor Company

50C02CH — NPN Epitaxial Planar Silicon Transistor Low-Frequency General-Purpose Amplifier Applications

Applications

- Low-frequency Amplifier, high-speed switching, small motor drive, muting circuit

Features

- Large current capacitance
- Low collector-to-emitter saturation voltage (resistance) $R_{CE(sat)}$ typ.=175m Ω [$I_C=0.5A$, $I_B=50mA$]
- Ultrasmall package facilitates miniaturization in end products
- Small ON-resistance (R_{on})

Specifications

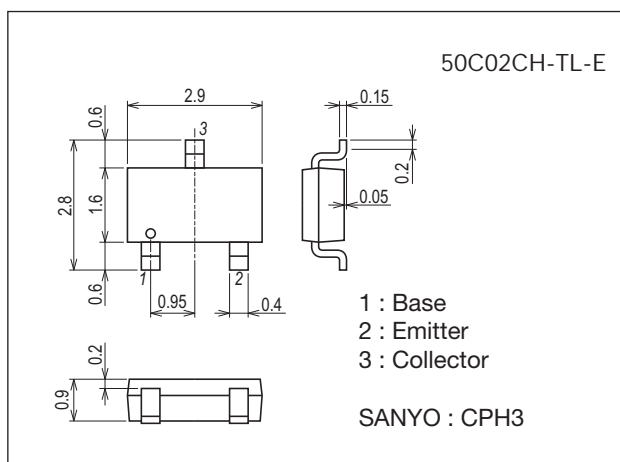
Absolute Maximum Ratings at $T_a=25^\circ C$

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V_{CBO}		60	V
Collector-to-Emitter Voltage	V_{CEO}		50	V
Emitter-to-Base Voltage	V_{EBO}		5	V
Collector Current	I_C		500	mA
Collector Current (Pulse)	I_{CP}		1.0	A
Collector Dissipation	P_C	Mounted on a ceramic board (600mm ² ×0.8mm)	700	mW
Junction Temperature	T_j		150	$^\circ C$
Storage Temperature	T_{stg}		-55 to +150	$^\circ C$

Package Dimensions

unit : mm (typ)

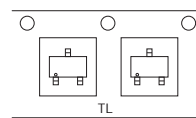
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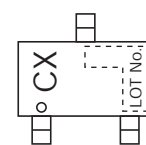
Product & Package Information

- Package : CPH3
- JEITA, JEDEC : SC-59, TO-236, SOT-23
- Minimum Packing Quantity : 3,000 pcs./reel

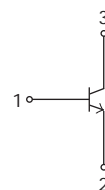
Packing Type: TL



Marking



Electrical Connection



SANYO Semiconductor Co., Ltd.

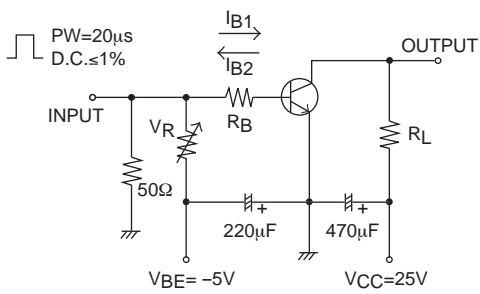
<http://semicon.sanyo.com/en/network>

50C02CH

Electrical Characteristics at $T_a=25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I_{CBO}	$V_{CB}=40\text{V}, I_E=0\text{A}$			100	nA
Emitter Cutoff Current	I_{EBO}	$V_{EB}=4\text{V}, I_C=0\text{A}$			100	nA
DC Current Gain	h_{FE}	$V_{CE}=2\text{V}, I_C=10\text{mA}$	300		800	
Gain-Bandwidth Product	f_T	$V_{CE}=10\text{V}, I_C=50\text{mA}$		500		MHz
Output Capacitance	C_{ob}	$V_{CB}=10\text{V}, f=1\text{MHz}$		2.8		pF
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=100\text{mA}, I_B=10\text{mA}$		50	100	mV
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=100\text{mA}, I_B=10\text{mA}$		0.9	1.2	V
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=10\mu\text{A}, I_E=0\text{A}$	60			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=1\text{mA}, R_{BE}=\infty$	50			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E=10\mu\text{A}, I_C=0\text{A}$	5			V
Turn-On Time	t_{on}	See specified Test Circuit.		30		ns
Storage Time	t_{stg}			340		ns
Fall Time	t_f			55		ns

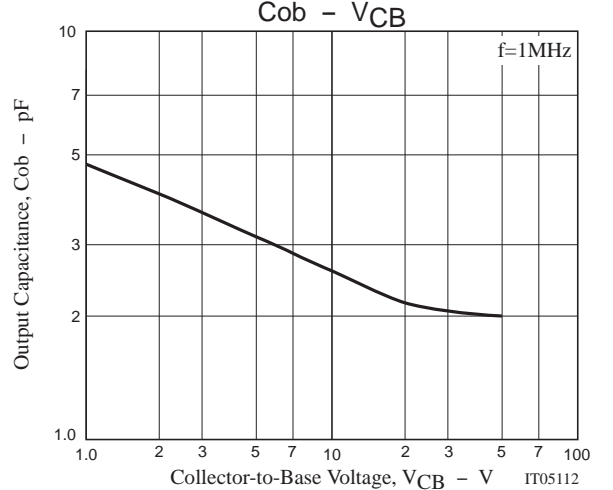
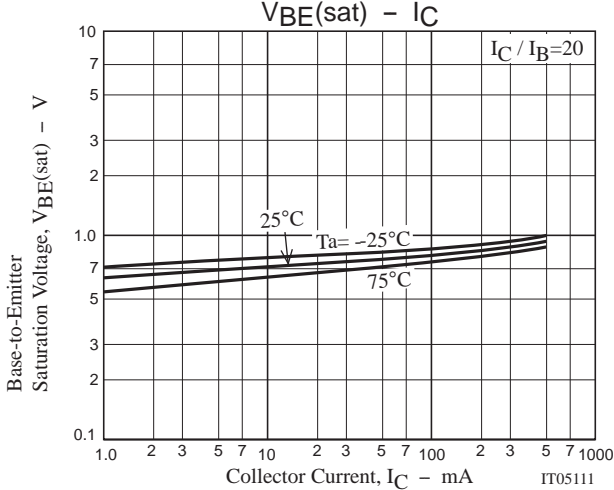
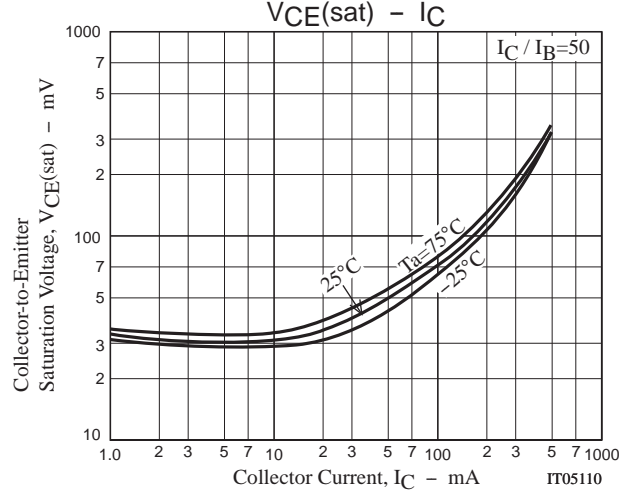
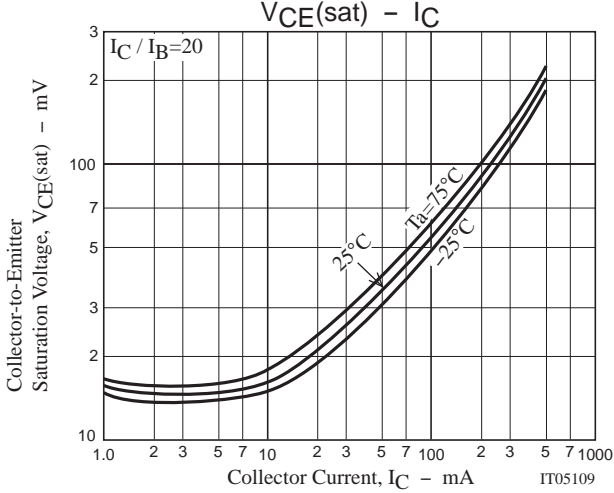
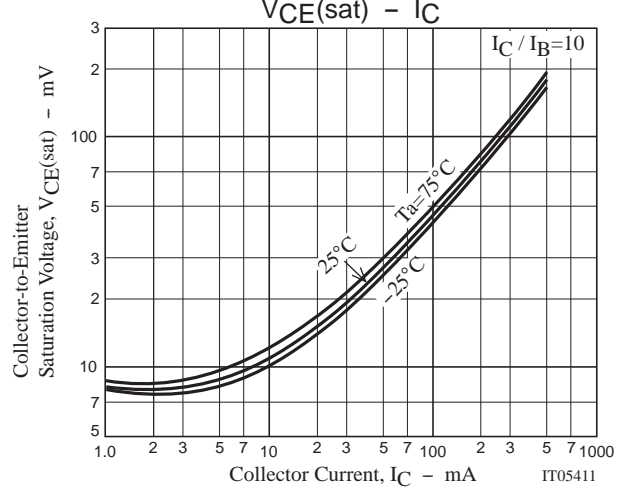
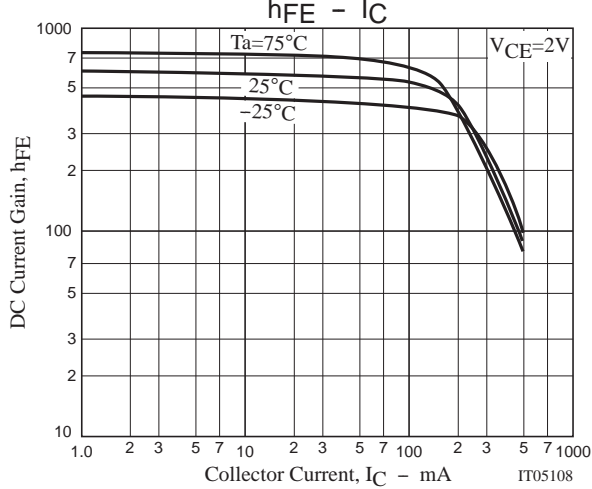
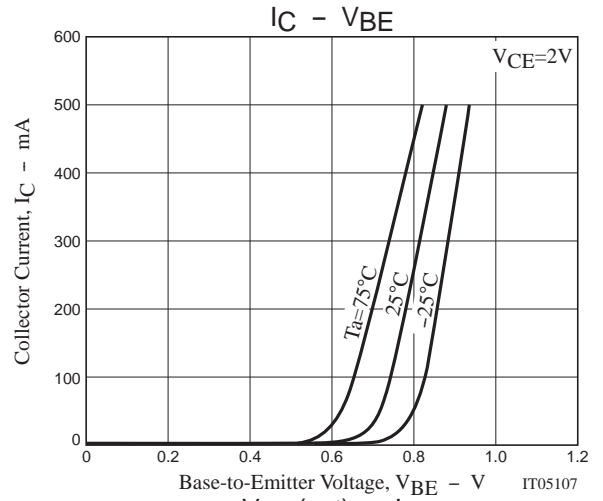
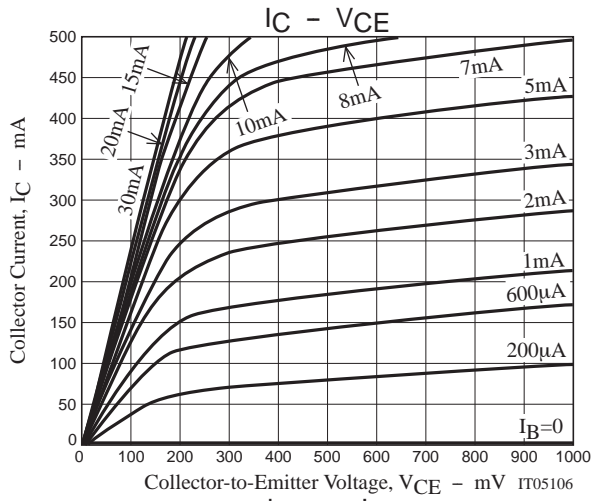
Switching Time Test Circuit



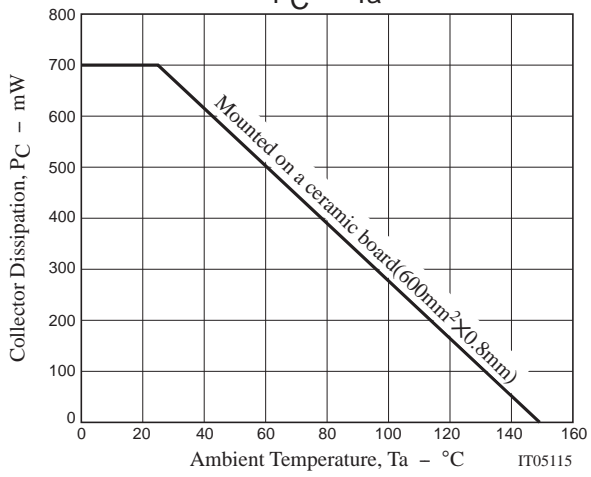
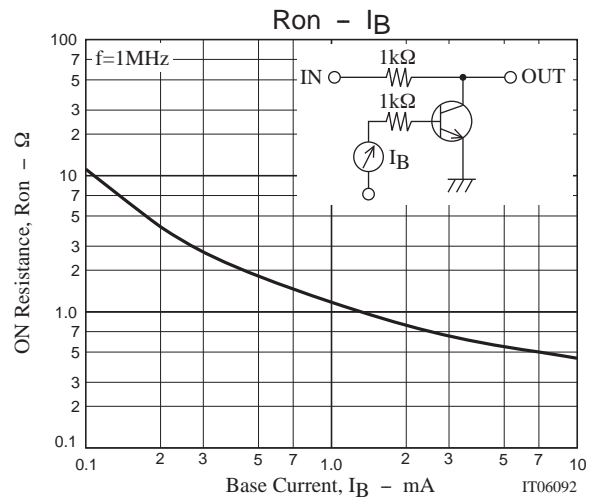
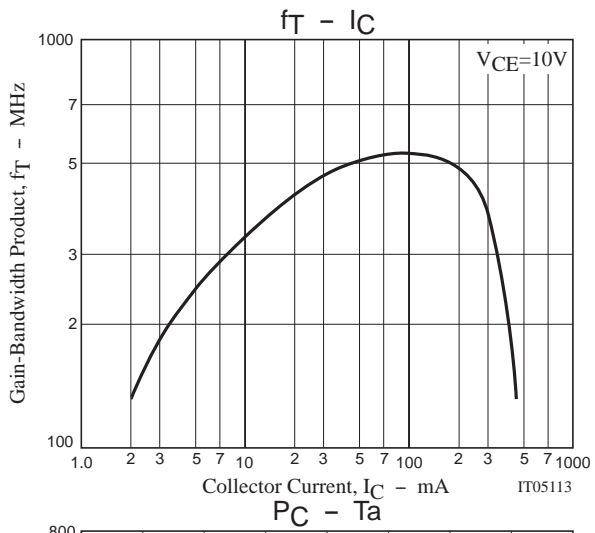
$$I_C=20I_{B1}=-20I_{B2}=200\text{mA}$$

Ordering Information

Device	Package	Shipping	memo
50C02CH-TL-E	CPH3	3,000pcs./reel	Pb Free



50C02CH



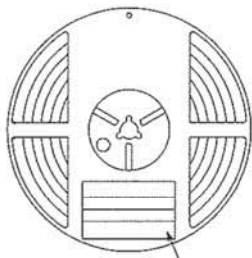
Embossed Taping Specification

50C02CH-TL-E

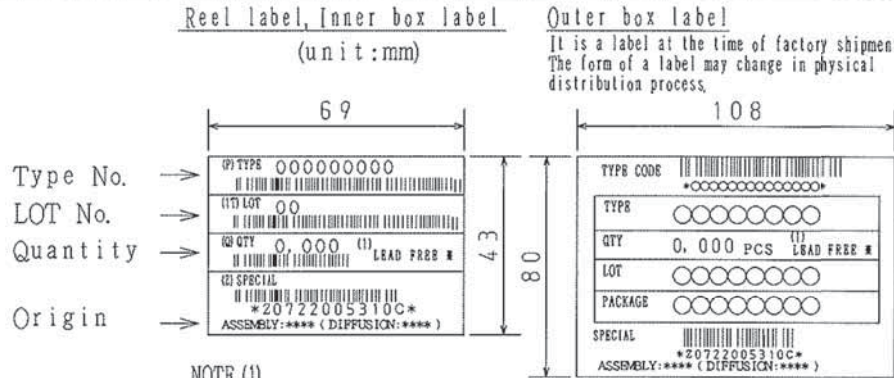
1. Packing Format

Package Name	Carrier Tape Type	Maximum Number of devices contained (pcs)			Packing format	
		Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)
CPH3	CPH3	3,000	15,000	90,000	5 reels contained Dimensions:mm (external) 183×72×185	6 inner boxes contained Dimensions:mm (external) 440×195×210

Packing method



Reel label



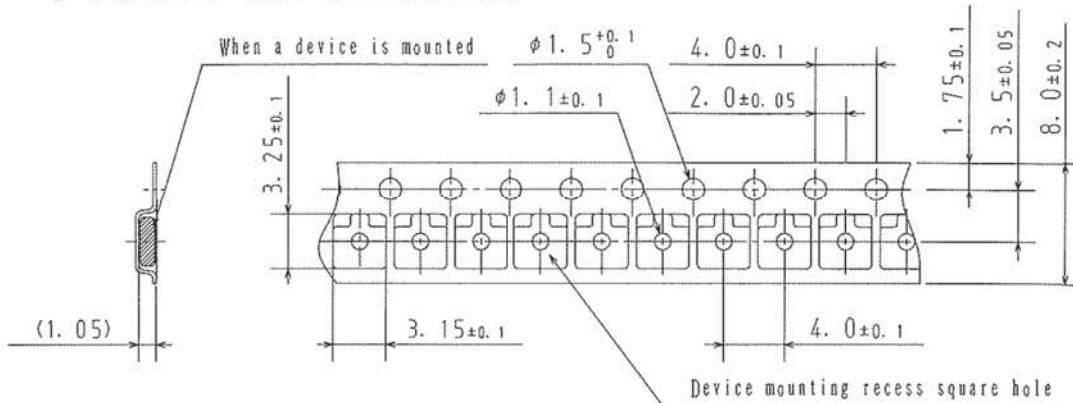
NOTE (1)

The LEAD FREE * description shows that the surface treatment of the terminal is lead free.

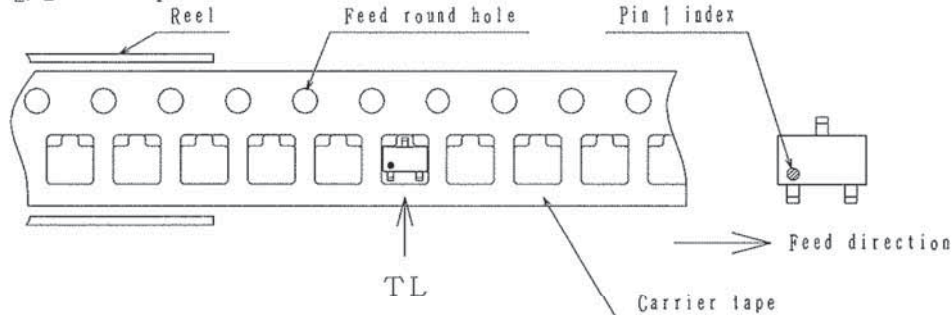
Label	JEITA Phase
LEAD FREE 3	JEITA Phase 3A
LEAD FREE 4	JEITA Phase 3

2. Taping configuration

2-1. Carrier tape size (unit:mm)



2-2. Device placement direction



Those with one electrode terminal on the feed hole side.....TL

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